NSN 5961-00-411-3079

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-411-3079 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 reverse voltage, dc **Current Rating Per Characteristic:** 20.00 microamperes source cutoff current of standard range **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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